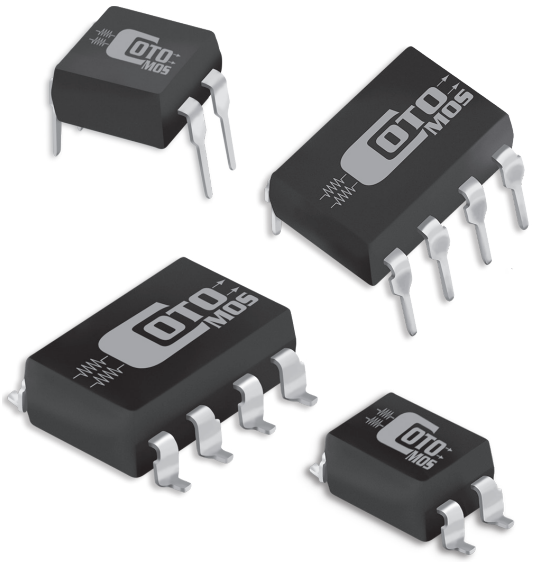


CotoMOS® CT570 / CS570 / CT670 / CS670

The CT570 / CS570 / CT670 / CS670 features current switching capability to 440mA with a low on resistance of 1.6Ω Maximum. Designed for Security, Measurement and Instrumentation applications the 70 Series relay is capable of handling 60V load conditions. If your requirements are different please contact your Coto Applications Engineer for assistance through www.cotorelay.com.

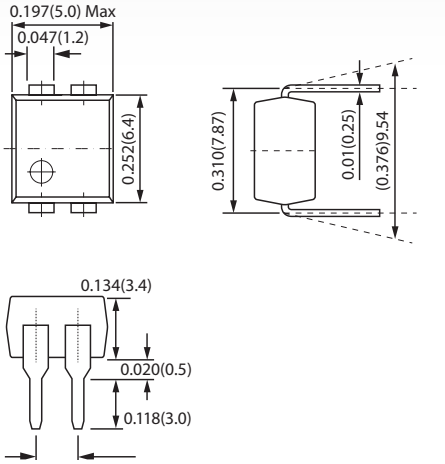
CT570 / CS570 / CT670 / CS670 Features

- Contact Form: 1B/2B
- Load Voltage: 60V Maximum
- Operation LED Current: 3.0mA Maximum
- Load Current: 440mA Maximum
- On-Resistance: 1.6Ω Maximum
- Output Capacitance: 165pF Typical
- Low Off-State Leakage Current: 10μ A Maximum

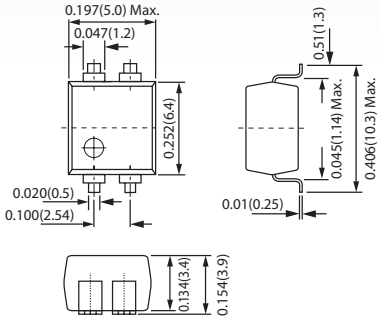
DIMENSIONS

in Inches (Millimeters)

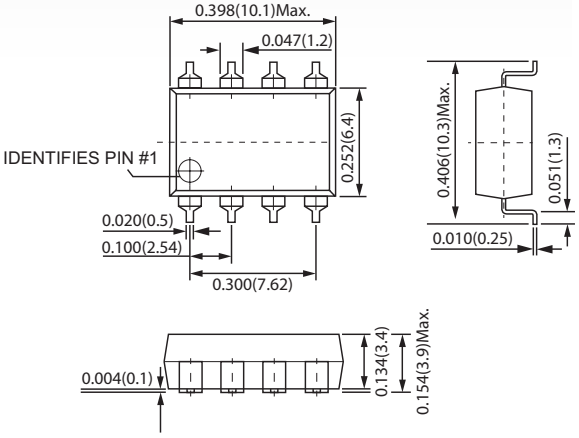
CT570



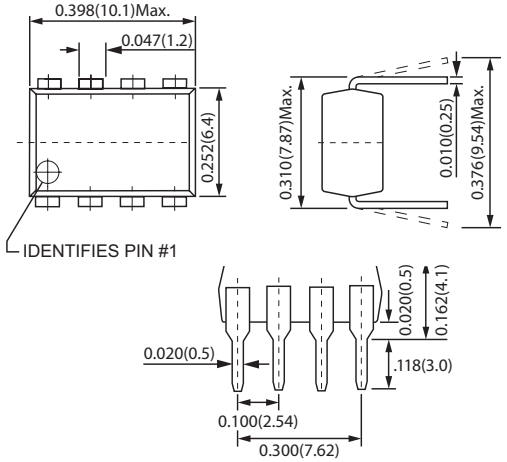
CS570



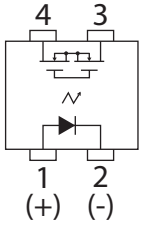
CS670



CT670

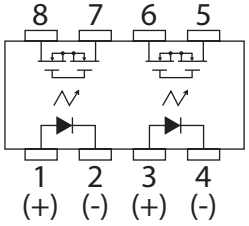


TERMINAL IDENTIFICATION



1: Anode (LED) 2: Cathode (LED)	3,4: Drain (MOSFET)

TERMINAL IDENTIFICATION



1,3: Anode (LED) 2,4: Cathode (LED)	5,6,7,8: Drain (MOSFET)

04182016

tel: (401) 943.2686 | fax: (401) 942.0920

CT570 / CS570 / CT670 / CS670 MAXIMUM RATINGS (Ambient Temperature: 25°C)

Parameters	Symbol	Units	Value (DIP or SMD 4/8)
INPUT SPECIFICATIONS			
Continuous LED Current	I_F	mA	50
Peak LED Current	I_{FP}	mA	500
LED Reverse Voltage	V_R	V	5
Input Power Dissipation	P_{in}	mW	75
OUTPUT SPECIFICATIONS			
Load Voltage	V_L	V (AC peak or DC)	60
Load Current	I_L	mA	440 / 380
Peak Load Current	I_{Peak}	A	600 / 600
Output Power Dissipation	P_{Out}	mW	450 / 600
RELAY SPECIFICATIONS			
Total Power Dissipation	P_T	mW	500 / 650
I/O Breakdown Voltage	$V_{I/O}$	Vrms	1500
Operating Temperature	T_{Opr}	°C	-40 ~ +85
Storage Temperature	T_{Stg}	°C	-40 ~ +100

CT570 / CS570 / CT670 / CS670 ELECTRICAL SPECIFICATIONS (Ambient Temperature: 25°C)

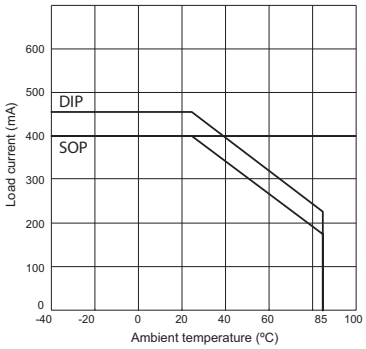
Parameters	Symbol	Test Conditns	Units	Min	Typ	Max
INPUT						
LED Forward Voltage	V_F	I_F=10mA	V	1.0	1.17	1.5
Operation LED Current	$I_{F\ On}$		mA		0.9	3.0
Recovery LED Voltage	$V_{F\ Off}$		V	0.5	1.0	
OUTPUT						
On-Resistance Drain to Drain	R_{On}	I_F=0mA, I_L=Rating Time to flow is within 1 sec.	Ω		0.75	1.6
Off-State Leakage Current	I_{Leak}	I_F=10mA, V_L=60V	µA			10
Output Capacitance	C_{Out}	I_F=10mA, V_L=0V, f=1MHz	pF		165	
TRANSMISSION						
Operate Time	T_{On}	I_F=10mA, I_L=Rating	ms		0.25	2.0
Recovery Time	T_{Off}	I_F=10mA, I_L=Rating	ms		0.05	1.0
COUPLED						
I/O Insulation Resistance	$R_{I/O}$		Ω	10^9		
I/O Capacitance	$C_{I/O}$	f=1MHz	pF		1.3	

Environmental Ratings:

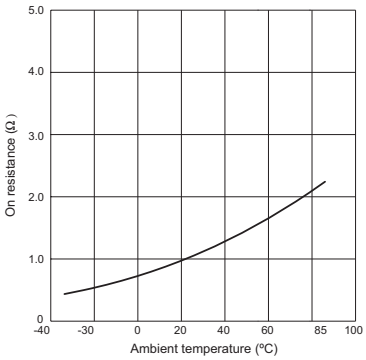
Operating Temp: -40°C to +85° C; Storage Temp: –40 to +100 C.
All electrical parameters measured at 25° C unless otherwise specified.

470/570/670 SERIES GRAPHS

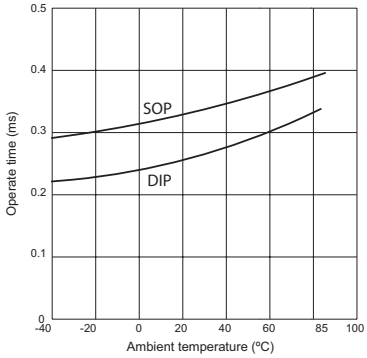
Load current Vs.
Ambient temperature



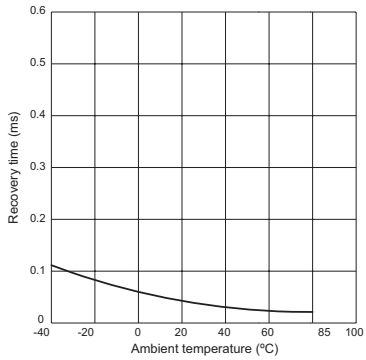
On resistance Vs.
Ambient temperature



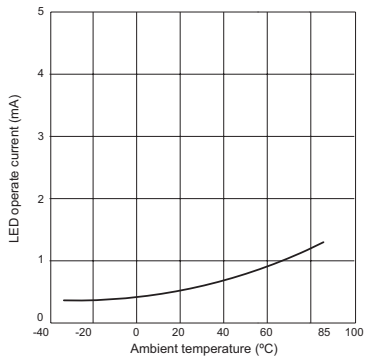
Operate time Vs.
Ambient temperature



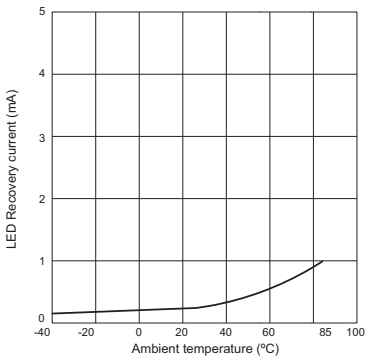
Recovery time Vs.
Ambient temperature



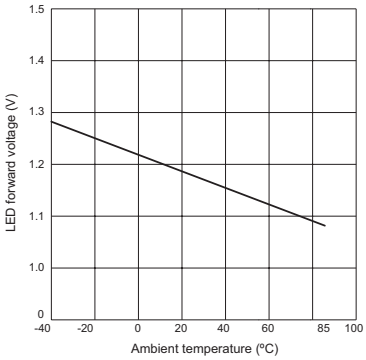
LED operate current Vs.
Ambient temperature



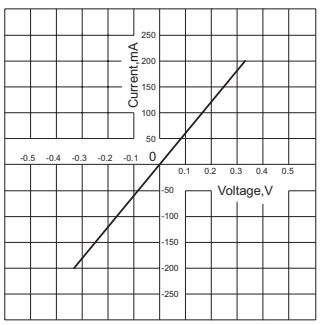
LED Recovery current Vs.
Ambient temperature



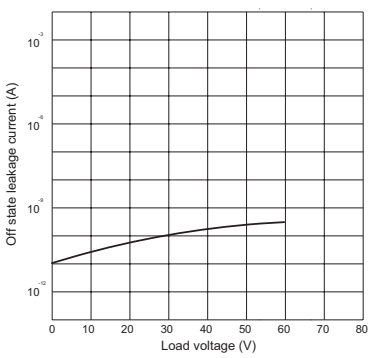
LED forward voltage Vs.
Ambient temperature



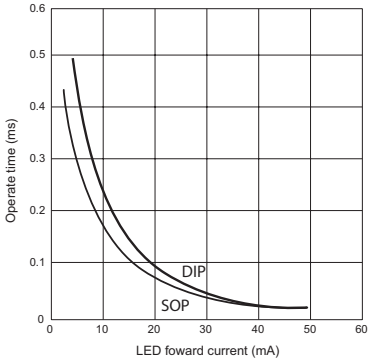
Voltage Vs. current characteristics
of output at MOS portion



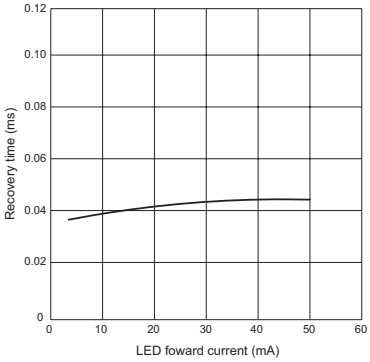
Off state leakage current



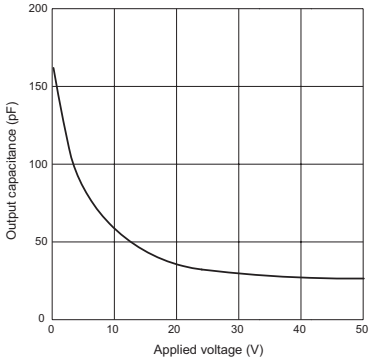
LED foward current Vs.
operate time characteristics



LED foward current Vs.
recovery time characteristics



Applied voltage Vs.
output capacitance characteristics



02252015